

Application Brief

Space-Grade, 50-krad, Overcurrent Event-Detection Circuit



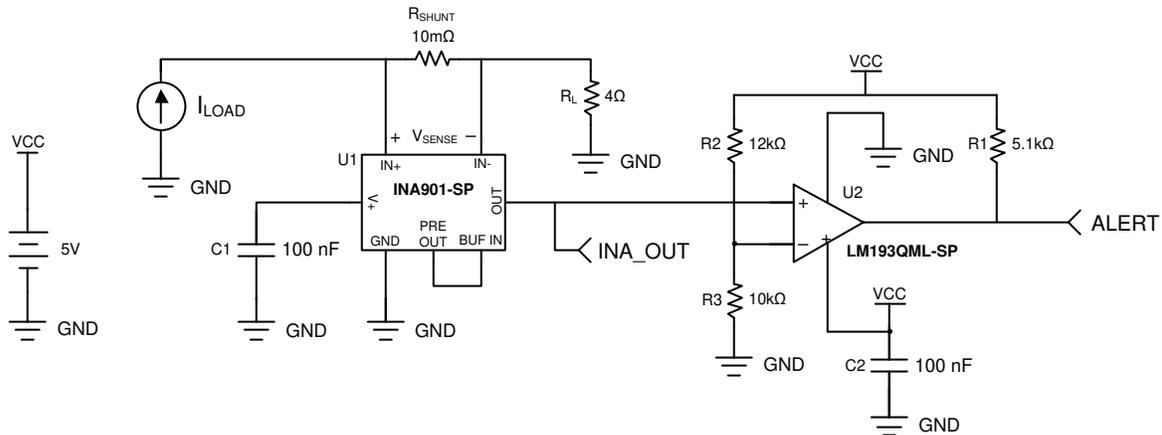
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Design Goals

Input		Overcurrent Conditions	Output	Supply	Response Time	Total Ionizing Dose	Single Event Immunity
$I_{load\ Min}$	$I_{load\ Max}$	I_{OC_TH}	V_{out_OC}	V_S	t_{delay}	TID	SEL
5A	10A	11A	2.2V	5V	< 5 μ s	50 krad (Si)	75 MeV \times cm ² /mg

Design Description

This is a unidirectional current-sensing solution, generally referred to as overcurrent protection (OCP) that can provide an overcurrent alert signal to power off a system exceeding a threshold current. In this particular setup, the normal operating load is from 5A to 10A, with the overcurrent threshold defined at 11A (I_{OC_TH}). The current shunt monitor and comparator are powered from a single 5-V supply rail. OCP can be applied to both high-side and low-side topologies. The solution presented in this circuit is a high-side implementation, with R_L placed as a representation of a purely resistive system load at 4 Ω . This circuit is useful in a variety of power applications for telemetry, health monitoring and system diagnostics. In addition to this functionality, this circuit implements the [INA901-SP](#), which is a Radiation-Hardness-Assured (RHA), 50-krad(Si) capable device at Low Dose Rate, that is also Single Event Latch-up (SEL) Immune to 75 MeV \times cm²/mg at 125 $^{\circ}$ C. The comparator function is fulfilled by a [LM193QML-SP](#), but the [LM139AQML-SP](#) can be used here as well, if additional comparator device count is needed.



Design Notes

- For accurate comparator applications without hysteresis, it is important to maintain a stable power supply with minimized noise and glitches. To achieve this, use decoupling capacitors C1 and C2 to ensure device supplies are stable. Place the decoupling capacitors as close as possible to the supply pins of their respective devices. This should also be implemented on the negative supply of the comparator, if used.
- If a larger dynamic current measurement range is required with a higher trip point, a voltage divider from the [INA901-SP](#) OUT pin to ground can be incorporated with the divider output going to the [LM193QML-SP](#) input. Ensure that the designed range of the [INA901-SP](#) remains within the input common-mode specification of the [LM193QML-SP](#).
- If additional short circuit to ground protection is needed in the circuit, fuses in series with the input pins can provide this functionality, but resistors should not be used for this purpose. Addition of resistors to the input pins of the [INA901-SP](#) will fundamentally change the gain of the amplifier. However, the tolerance of the internal resistors will fluctuate up to 30% (these resistors are matched to one another, rather than an absolute value), and thus this change in gain will vary from device to device, and cannot be considered reliable design.

Design Steps

- Full Scale Range:** Determine the load range of conditions needing to be monitored. Choice of R_{SHUNT} should be made with respect to the maximum range of current allowable to the input sense voltage, including the overcurrent value. Additional considerations are offset voltage on the lower end of measurement, and maintaining a valid common mode voltage on the input pins of the [LM193QML-SP](#). While designing with [INA901-SP](#), for best performance, ensure that the I_{MIN} condition with the chosen shunt produces a sense voltage $> 20mV$ to comply with the *Accuracy Variations as a Result of V_{SENSE} and Common-Mode Voltage* section of the [INA901-SP Radiation Hardened, -15-V to 65-V Common Mode, Unidirectional Current-Shunt Monitor Data Sheet](#).
- Gain Options:** For the [INA901-SP](#), only a 20V/V option is available, so this condition is fixed for this design.
- Choosing a shunt resistor:** Given the design conditions, choose an appropriate shunt using the following equation. Note that there is a 200-mV reduction on the supply voltage to ensure that the device meets swing-to-rail limitations of the device. Numerical values come from the previously-defined use case:

$$R_{SHUNT,MAX} < \frac{V_S - 0.2}{I_{LOAD,MAX} \times GAIN}$$

$$R_{SHUNT,MAX} < \frac{5 - 0.2}{11 \times 20} = 21.8m\Omega$$

A shunt resistor value of 10m Ω is chosen for the design. Be aware that while a larger shunt provides more utilization of the full scale range, thermal constraints on the shunt will increase proportionally with the resistance. Selection of a higher value will also increase the voltage of the overcurrent trip point, which may cause challenges in satisfying the common-mode requirement of the [LM193QML-SP](#).

- Setting the overcurrent point:** From the [INA901-SP](#), with the value of R_{SHUNT} now determined, it is found that the output of the [INA901-SP](#) at the overcurrent point is:

$$V_{OUT_{OC}} = I_{LOAD_{OC}} \times R_{SHUNT} \times GAIN = 11A \times 10m\Omega \times 20 = 2.2V$$

The overcurrent condition is set by a voltage divider between R2 and R3 set for the previously-mentioned point. Choose a value for R3 and calculate the needed resistor R2. Here, R3 is chosen at 10k Ω :

$$\frac{10k\Omega}{10k\Omega + R2} \times V_{CC} = 2.2V$$

$$R2 = 12.73k\Omega$$

Note that the [LM193QML-SP](#) requires that at least one input be from 0V to 3V when operating at a supply of 5V to satisfy the input common-mode requirement. This node held at a constant 2.2V satisfies this requirement for all values of comparison.

Often, calculated resistor values will not directly align with available resistor choices. Here, 12.73kΩ is not a standard value, so the closest standard value of 12kΩ is selected. The actual overcurrent point based on the resistor value can be found by combining the previous equations.

$$I_{LOAD_{oc}} = \left(\frac{R1}{R1 + R2} \right) \frac{V_{CC}}{R_{SHUNT} \times GAIN} = \left(\frac{10k\Omega}{10k\Omega + 12k\Omega} \right) \left(\frac{5V}{10m\Omega \times 20} \right) = \mathbf{11.36A}$$

5. **Offset error check:** Check that the minimum meaningful current measurement is significantly higher than the current shunt monitor input offset voltage. The recommended maximum error from offset, eVOS is 10%. The value of eVOS can be lowered for tighter error targets:

$$I_{DEVICE_MIN} = \frac{V_{OS, worst\ case}}{\frac{eVOS}{100} \times R_{SHUNT}} = \frac{3.5mV}{\frac{10}{100} \times 0.01\Omega} = 3.5A$$

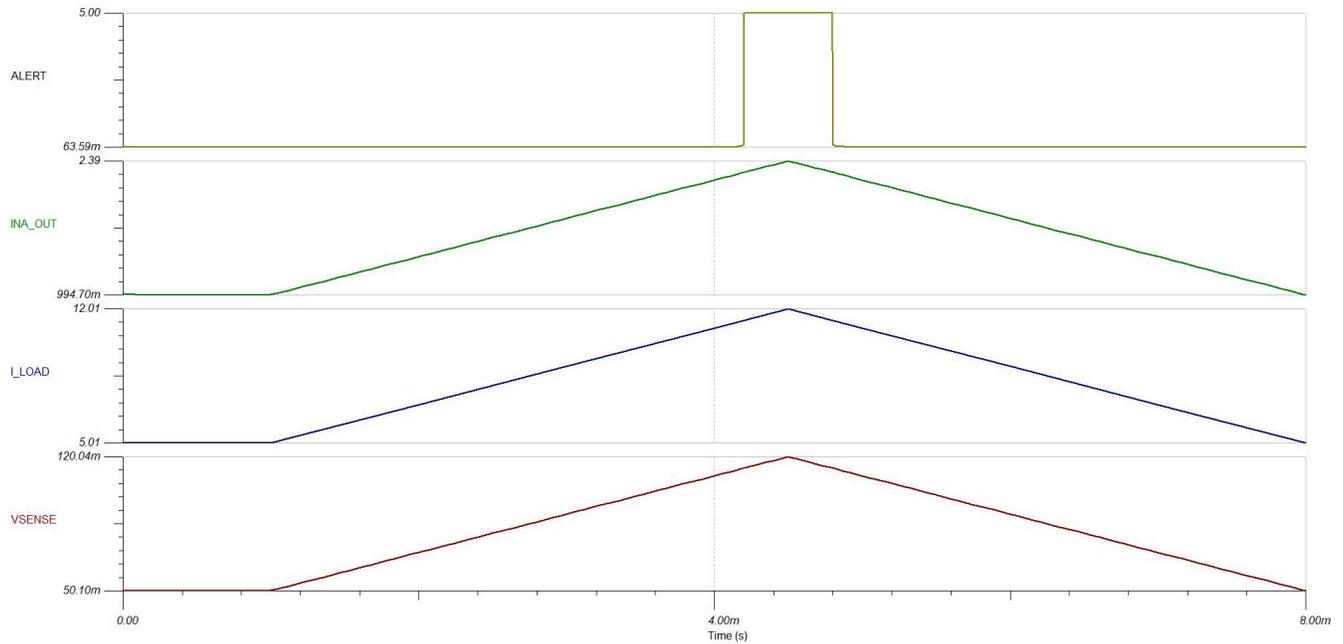
This value means that at a measured current of 3.5A for the chosen shunt, offset voltage will contribute a 10% error to the measurement.

Design Simulations

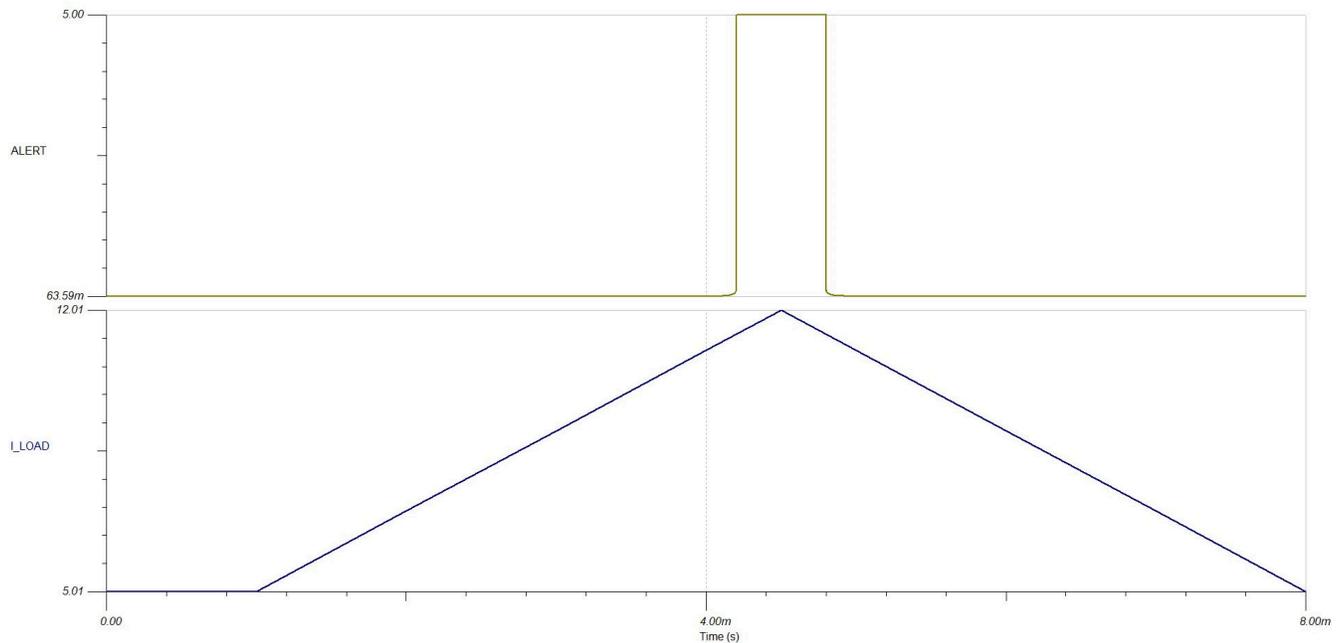
Transient Simulation Results

High-Side OCP Simulation Results

The first simulation examines the ramp response of the circuit, as the current transitions above the overcurrent trigger point.

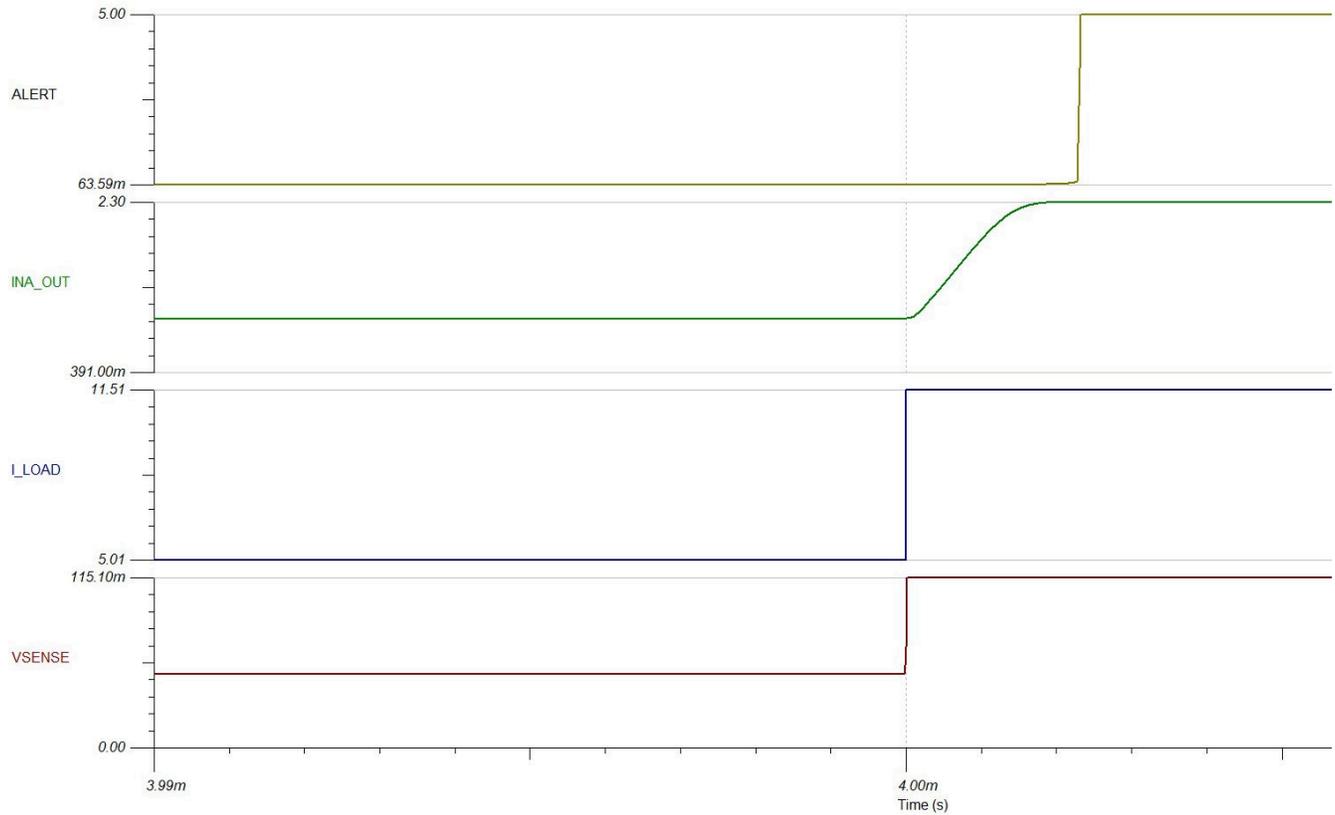


INA901-SP Overcurrent Ramp Response



INA901-SP Overcurrent Ramp Response, Zoom In

Next, examining the delay response of the circuit, with a step response delivered at 4.0ms, it is shown that the circuit responds to the event approximately 2.5 μ s later, so the delay response is satisfied:



INA901-SP Overcurrent Protection Step Response

Design References

See the TI Precision Labs, [Current Sense Amplifiers](#) video series.

Design Featured Current Sense Amplifier

INA901-SP	
V_S	2.7V to 16V
V_{CM}	-15V to 65V
V_{OUT}	GND+3mV to V_S -50mV, typical
V_{OS}	$\pm 500\mu V$, typical
I_q	350 μA , typical
I_B	$\pm 8\mu A$, typical
TID Characterization (ELDRS-Free)	50krad (Si)
SEL Immune to LET	75 MeV-cm ² /mg
https://www.ti.com/product/INA901-SP	

For less harsh radiation environments, TI also offers the [INA240-SEP](#), which offers Single Event Latch-up (SEL) Immunity to 43 MeV-cm²/mg at 125°C. It is ELDRS Free to 30 krad(Si), and Total Ionizing Dose (TID) RLAT for Every Wafer Lot is up to 20 krad(Si):

Table 2. Design Alternate Current Sense Amplifier

INA240-SEP	
V_S	2.7V to 5.5V
V_{CM}	-4V to 80V
V_{OUT}	GND+1mV to V_S -50mV, typical
V_{OS}	$\pm 5\mu V$, typical
I_q	1.8mA, typical
I_B	$\pm 90\mu A$, typical
TID Characterization (ELDRS-Free)	30 krad (Si)
SEL Immune to LET	43 MeV-cm ² /mg
https://www.ti.com/product/INA240-SEP	

Table 3. Design Alternate Comparator

	TLV1704-SEP	LM139AQL-SP
V_S	2.2V to 36V	2V to 36V
V_{CM}	Rail-to-Rail	0V to 34V
V_{OUT}	Open-Collector, Rail-to-Rail	Open-Collector
V_{OS}	500 μV	2mV
I_q	55 μA /channel	200 μA /channel
$t_{PD(HL)}$	460ns	2.50 μs
TID Characterization (ELDRS-Free)	30 krad (Si)	100 krad (Si)
SEL Immune to LET	43 MeV-cm ² /mg	SEL Immune (Bipolar process)
	https://www.ti.com/product/TLV1704-SEP	https://www.ti.com/product/LM139AQL-SP

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